

12500 TI Boulevard, MS 8640, Dallas, Texas 75243

PCN# 20211220003.1

Qualification of new Fab site (RFAB) using qualified Process Technology, Die Revision, and additional Assembly & BOM option for select devices Change Notification / Sample Request

Date: December 29, 2021 **To:** PREMIER FARNELL PCN

Dear Customer:

This is an announcement of a change to a device that is currently offered by Texas Instruments. The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) <u>process.</u>

TI requires acknowledgement of receipt of this notification within **30** days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If samples or additional data are required, requests must be received within **30 days** of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's previous announcement to close our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team (PCN www admin team@list.ti.com). For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

PCN Team SC Business Services

20211220003.1 Attachments.1

Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the past twenty-four (24) months. The corresponding customer part number is also listed, if available.

Technical details of this Product Change follow on the next page(s).

PCN Number:		20211220003.1						PCN Date:		December 29, 2021			
Title: Qualification of new Fab and additional Assembly										Techno	ology,	Die Revision,	
Cus	stome	er Conta	ct:	PCN A	Nanager		Dept: Quality Services						
Proposed 1 st Ship Date: Mar			Mar 2	8, 2	2022	Estimated Sample Date provide Availability: sample requ		•					
Cha	ange	Type:											
\boxtimes	Asse	mbly Sit	e			\boxtimes	Design				Wafei	r Bumj	p Site
	Asse	mbly Pro	cess				Data S	heet			Wafei	r Bumj	p Material
Assembly Materials					Part number change			Wafei	r Bumj	p Process			
Mechanical Specification				Test Site		\boxtimes	Wafei	r Fab S	Site				
Packing/Shipping/Labeling			ng		Test Pr	ocess		\boxtimes	Wafei	r Fab I	Materials		
								Wafei	r Fab F	Process			
	DCN Detaile												

PCN Details

Description of Change:

Texas Instruments is pleased to announce the qualification of a new fab & process technology (RFAB, LBC9) and Assembly & BOM option for selected devices as listed below in the product affected section. Construction differences are noted below:

С	urrent Fab Site	е	Additional Fab Site			
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter	
SFAB	HCMOS	150 mm	RFAB	LBC9	300 mm	

The die was also changed as a result of the process change.

Additionally, there will be a BOM/Assembly options introduced for these devices:

Group 1 - RFAB/Process migration & BOM Update for Select PW, N NS, DW, DB, & D **Packaged Devices**

	Current	Additional			
Bond wire diameter (Cu)	0.96 mils	0.8 mils			

Group 2 - RFAB/Process migration BOM update & TFME as alternate Assembly site for **PW Packaged devices**

	MLA Current	MLA New	TFME
Bond wire diameter (Cu)	0.96 mil	0.8 mils	0.8 mils
Mold Compound	4211471	4211471	SID#R-31
Mount Compound	4147858	4147858	SID# A-03
Lead Finish	NiPdAu	NiPdAu	Matte Sn

Group 3 - RFAB/Process migration, BOM update & HFTF as alternate Assembly site for **SOIC Packaged Devices**

	MLA Current	MLA New	HFTF
Bond wire diameter (Cu)	0.96 mil	0.8 mils	0.8 mils
Mount Compound	4147858	4147858	SID#A-03
Mold Compound	4211880	4211880	SID#R-30
Lead Finish	NiPdAu	NiPdAu	Matte Sn

Upon expiry of this PCN TI will combine lead free solutions in a single standard part number, for the devices in group 3. For example; <u>SN74HCT04PWR</u> - can ship with both Matte Sn and NiPdAu/Ag.

Example:

- Customer order for 7500 units of SN74HCT04PWR with 2500 units SPQ (Standard Pack Quantity per Reel).
- TI can satisfy the above order in one of the following ways.
 - I. 3 Reels of NiPdAu finish.
 - II. 3 Reels of Matte Sn finish
 - III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish.
 - IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.

The following table provides the updated thermal characteristics to all devices contained within this PCN. All thermal values can be compared to the existing devices by reviewing the datasheets currently on TI.com. The impact to the customer system is anticipated to be negligible, however the customer must review their system design to assess any risk due to the change in thermal characteristics. Please see the table below which provides a summary of thermal values that the devices will be updated to based on each pin/pkg combination:

	THERMAL METRIC		D (SOIC)	PW (TSSOP)	DB (SSOP)	DW (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT
			16 PINS	16 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	
RθJA	Junction-to-ambient thermal resistance	138.7	117.2	137.5	122.7	109.1	84.6	113.4	131.8	°C/W
RθJC(top)	Junction-to-case (top) thermal resistance	93.8	77.2	75.3	81.6	76	72.5	78.6	72.2	°C/W
RθJB	Junction-to-board thermal resistance	94.7	75.6	82.2	77.5	77.6	65.3	78.4	82.8	°C/W
ΨЈТ	Junction-to-top characterization parameter	49.1	38.1	25.1	46.1	51.5	55.3	47.1	21.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	94.3	75.3	81.8	77.1	77.1	65.2	78.1	82.4	°C/W
RθJC(bot)	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	°C/W

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-milimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
No Change	No Change	No Change	No Change ■ No Change ■ No Change No Change ■ No Change ■ No Change No Change

Changes to product identification resulting from this PCN:

Fab Site Information:

Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
SH-BIP-1	SHE	USA	Sherman
RFAB	RFB	USA	Richardson

Die Rev:

Current New

Die Rev [2P]	Die Rev [2P]
A,E,F,G,H,-	A, B

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
MLA	MLA	MYS	Kuala Lumpur
HFTFAT	HFT	CHN	Hefei
TFME	NFM	CHN	Economic Development Zone

Sample product shipping label (not actual product label)

TEXAS INSTRUMENTS MADE IN: Malaysia 2DC: 2Q:

MSL 2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM:

5A (L)T0:1750



(1P) SN74LS07NSR (a) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812 (2P) REV: 0033317

(201) CSO: SHE (211) GGO:USA (221) ASO: MLA (23L) ACO: MYS

Product Affected:

Group 1 Device list (RFAB/Process migration & BOM Update for select PW, N NS, DW, **DB**, & D Packaged Devices)

CD74F	HC688E	SN74HC374DWR	SN74HCT541NSR	SN74HCT240ANSF
SN74F	HC244N	SN74HC377DWR	SN74HCT541PWR	SN74HCT244ANSF
SN74F	HC688N	SN74HC540DWR	SN74HCT573DBR	SN74HCT244APWI
CD74F	HCT244E	SN74HC541DWR	SN74HCT573DWR	SN74HCT541APWI
CD74H	HCT373E	SN74HC563DWR	SN74HCT573NSR	CD74HCT541M96E
CD74H	HCT374E	SN74HC574DWR	SN74HCT574DWR	CD74HCT541M960
SN74F	HCT240N	SN74HC688DWR	SN74HCT574NE4	CD74HCT573M960
SN74F	HCT244N	SN74HC688NE4	SN74HCT574NSR	SN74HC244QPWR
SN74F	HCT373N	SN74HC688PWR	SN74HCT574PWR	SN74HC573ADWR
SN74F	HCT374N	CD74HCT244M96	CD74HC244M96E4	SN74HCT240DWR
SN74F	HCT541N	CD74HCT374EE4	CD74HC244M96G4	SN74HCT244DWR
SN74F	HCT573N	CD74HCT541M96	CD74HC273M96E4	SN74HCT244DWR
SN74F	HCT574N	CD74HCT573M96	CD74HC541M96G4	SN74HCT244NSR0
CD74H	HC244M96	CD74HCT574PWR	CD74HC564M96E4	SN74HCT244PWR
CD74H	HC273M96	SN74HC244APWR	CD74HC573M96G4	SN74HCT373DWR
CD74H	HC373M96	SN74HC573ADWR	CD74HC574M96E4	SN74HCT373PWRI

		•	•
CD74HC541M96	SN74HCT240DWR	CD74HC574M96G4	SN74HCT374DWRE4
CD74HC564M96	SN74HCT240NSR	CD74HC688M96E4	SN74HCT541DWRE4
CD74HC573M96	SN74HCT240PWR	SN74HC241DWRG4	SN74HCT541DWRG4
CD74HC574M96	SN74HCT244DBR	SN74HC244DWRE4	SN74HCT541NSRE4
CD74HC688M96	SN74HCT244DWR	SN74HC244DWRG4	SN74HCT541NSRG4
CD74HC688NSR	SN74HCT244NE4	SN74HC244NSRG4	SN74HCT541PWRE4
CD74HC688PWR	SN74HCT244NSR	SN74HC244PWRE4	SN74HCT541PWRG4
SN74HC240DWR	SN74HCT244PWR	SN74HC244PWRG4	SN74HCT573DBRG4
SN74HC241DWR	SN74HCT373DWR	SN74HC373DWRE4	SN74HCT573DWRE4
SN74HC244DBR	SN74HCT373NE4	SN74HC374DWRG4	SN74HCT573DWRG4
SN74HC244DWR	SN74HCT373PWR	SN74HC540DWRE4	SN74HCT574DWRG4
SN74HC244NE4	SN74HCT374DWR	SN74HC688DWRE4	SN74HCT574PWRG4
SN74HC244NSR	SN74HCT374NSR	SN74HC688DWRG4	SN74HCT244QPWRQ1
SN74HC244PWR	SN74HCT374PWR	SN74HC688PWRE4	SN74HC244QPWRG4Q1
SN74HC273DWR	SN74HCT541DWR	SN74HC688PWRG4	SN74HC573AQPWRG4Q1
SN74HC373DWR	SN74HCT541NE4		

Group 2 Device list (RFAB/Process migration BOM update & TFME as alternate Assembly site for select SOIC Packaged devices)

CD74HC112PWR	SN74HC175PWR	SN74HC368PWR

Group 3 Device list (RFAB/Process migration BOM Update & HFTF as alternate Assembly site for select PW packaged devices)

CD74HC73M96	SN74HC112DR	SN74HC368DR	CD74HCT21M96
SN74HC109DR	SN74HC175DR		



Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Typ e	Test Name / Condition	Duration	Qual Device: CD74HC73M96 HF <u>TF</u>	Qual Device: CD74HC73M96 M LA	Qual Device: CD74HCT21M96 M LA	Qual Device: SN74HC109DR M LA	Qual Device: SN74HC112DR HF <u>TF</u>	Qual Device: SN74HC112DR M LA	Qual Device: SN74HC175DR HF <u>TF</u>
CD M	ESD - CDM	1500 V	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	-	-
ED	Electrical Characterizati on	Per Datasheet Parameter s	-	Pass	Pass	Pass	-	-	-
HB M	ESD - HBM	5000V	-	1/3/0	1/3/0	1/3/0	-	-	-
LU	Latch-up	(Per JESD78)	-	1/6/0	1/6/0	1/6/0	-	-	-

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

H	Data Displayed as. Namber of lots / Total sample size / Total named											
	Туре	Test Name / Condition	Duration	Qual Device: SN74HC175DR MLA	Qual Device: SN74HC368DR_HFTF	Qual Device: SN74HC368DR_MLA	QBS Process Reference: SN74HCS74QPWRQ1	QBS Package Reference: SN74HCS74DR	QBS Package Reference: SN74HCS74QDRQ1			
	-	Wire Bond Pull (Cpk>1.67)	Wires	-	-	-	3/90/0	-	3/90/0			
	AC	Autoclave 121C	96 Hours	-	-	-	3/231/0	-	3/231/0			
	CDM	ESD - CDM	1500 V	-	-	-	-	3/9/0	-			
	CDM	ESD - CDM - Q100	1500V	-	-	-	1/3/0	-	-			
	CDM	ESD - CDM - Q100	2000V	-	-	-	-	-	1/3/0			
	ED	Electrical Distributions	Per Datasheet Parameters	-	-	-	Pass	Pass	Pass			
	ELFR	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/2400/0	-	-			
	HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	-	3/231/0	3/231/0	3/231/0			

Туре	Test Name / Condition	Duration	Qual Device: SN74HC175DR MLA	Qual Device: SN74HC368DR HFTF	Qual Device: SN74HC368DR MLA	QBS Process Reference: SN74HCS74QPWRQ1	QBS Package Reference: SN74HCS74DR	QBS Package Reference: <u>SN74HCS74QDRQ1</u>
НВМ	ESD - HBM	7000V	-	-	-	1/3/0	-	-
НВМ	ESD - HBM	8000V	-	-	-	-	-	1/3/0
HTOL	Life Test, 150C	300 Hours	-	-	-	3/231/0	3/231/0	1/77/0
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	3/135/0	-	3/135/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	-	-	3/231/0	-
LU	Latch-up	(Per JESD78)	-	-	-	1/6/0	-	1/6/0
PC	Preconditioning	Level 1-260C	-	-	-	9/828/0	4/1300/0	12/1038/0
тс	Temperature Cycle, -65/150C	500 Cycles	-	-	-	3/231/0	3/231/0	3/231/0
UHAST	Unbiased HAST 130C/85%RH	96 Hours	-	-	-	-	3/231/0	-
WBS	Wire Bond Shear (Cpk>1.67)	Wires	-	-	-	3/90/0	-	3/90/0

- QBS: Qual By Similarity

- QBS: Qual By Similarity
 Qual Device CD74HCT21M96_MLA is qualified at LEVEL1-260C
 Qual Device SN74HC112DR_MLA is qualified at LEVEL1-260C
 Qual Device SN74HC175DR_HFTF is qualified at LEVEL1-260C
 Qual Device SN74HC368DR_MLA is qualified at LEVEL1-260C
 Qual Device CD74HC73M96_HFTF is qualified at LEVEL1-260C
 Qual Device SN74HC175DR_MLA is qualified at LEVEL1-260C
 Qual Device SN74HC112DR_HFTF is qualified at LEVEL1-260C
 Qual Device CD74HC73M96_MLA is qualified at LEVEL1-260C
 Qual Device SN74HC109DR_MLA is qualified at LEVEL1-260C
 Qual Device SN74HC368DR_HFTF is qualified at LEVEL1-260C

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20210124-138251



Qualification Report

Approve Date 14-Sep-2021

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: SN74HC273NSR	Qual Device: SN74HC374NSR	QBS Product Reference: CD74HC377PWR	QBS Product Reference: SN74HC240PWR	QBS Product Reference: SN74HC241PWR	QBS Product Reference: SN74HC273PWR	QBS Product Reference: <u>SN74HC373PWR</u>
CDM	ESD - CDM	1500 V	1/3/0	-	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0
нвм	ESD - HBM	5000V	-	-	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	QBS Product Reference: SN74HC374PWR	QBS Product Reference: SN74HC540PWR	QBS Product Reference: SN74HC541PWR	QBS Product Reference: SN74HC573APWR	QBS Product Reference: SN74HC574PWR	QBS Product Reference: SN74HCT573PWR	QBS Process Reference: SN74HCS245QPWRQ1
AC	Autoclave 121C	96 Hours	-	-	-	-	-	-	1/77/0
CDM	ESD - CDM	1500 V	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0
EC	Electrical Characterization	Per Datasheet Parameters	-	-	-	-	-	-	3/90/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	-	-	-	-	1/77/0
НВМ	ESD - HBM	5000V	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0
HTOL	Life Test, 150C	300 Hours	-	-	-	-	-	-	1/77/0

Туре	Test Name / Condition	Duration	QBS Product Reference: SN74HC374PWR	QBS Product Reference: SN74HC540PWR	QBS Product Reference: SN74HC541PWR	QBS Product Reference: SN74HC573APWR	QBS Product Reference: SN74HC574PWR	QBS Product Reference: SN74HCT573PWR	QBS Process Reference: SN74HCS245QPWRQ1
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	-	-	-	1/45/0
LU	Latch-up	(Per JESD78)	1/6/0	1/6/0	1/6/0	1/3/0	1/6/0	1/6/0	1/3/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	-	-	-	-	1/77/0
WBP	Wire Bond Pull	Wires	-	-	-	-	-	-	1/30/0
WBS	Wire Bond Shear	Wires	-	-	-	-	-	-	1/30/0

Туре	Test Name / Condition	Duration	QBS Process Reference: SN74HCS273QPWRQ1	QBS Package Reference: <u>1P8T245NSR</u>	QBS Package Reference: SN74HC253NSR	QBS Package Reference: SN74HC257NSR	QBS Package Reference: <u>ULQ2003AQDRQ1_RLF</u>	QBS Package Reference: ULQ2003AQDRQ1_STDLF
AC	Autoclave 121C	96 Hours	1/77/0	3/231/0	-	-	3/231/0	3/231/0
CDM	ESD - CDM	1500 V	1/3/0	-	1/3/0	-	-	-
EC	Electrical Characterization	Per Datasheet Parameters	No Fails	-	-	-	No Fails	-
HAST	Biased HAST, 130C/85%RH	96 Hours	1/77/0	-	-	-	-	3/231/0
HTOL	Life Test, 150C	300 Hours	1/77/0	-	-	-	-	-
HTOL	Life Test, 150C	408 Hours	-	-	-	-	-	3/231/0
HTSL	High Temp Storage Bake 150C	1000 Hours	1/45/0	-	-	-	1/45/0	1/45/0
HTSL	High Temp Storage Bake 170C	420 Hours	-	3/231/0	-	-	-	-
LU	Latch-up	(Per JEDC78)	1/6/0	-	-	-	-	-
тс	Temperature Cycle, -65/150C	500 Cycles	1/77/0	3/231/0	-	-	3/231/0	3/231/0
WBP	Wire Bond Pull	Wires	1/30/0	-	-	-	-	-
WBS	Wire Bond Shear	Wires	1/30/0	-	-	-	-	-

- QBS: Qual By Similarity
 Qual Device SN74HC374NSR is qualified at LEVEL1-260C
 Qual Device SN74HC273NSR is qualified at LEVEL1-260C
 Qual Device SN74HC273NSR is qualified at LEVEL1-260C
 Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTDL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent TEmp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles
 Quality and Environmental data is available at Ti's external Web site: http://www.ti.com/

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green TI Qualification ID: 20210125-138306



TI Information Selective Disclosure

Approve Date 12-Dec-2021

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: <u>CD74HC564M</u> <u>96</u>	Qual Device: SN74HC273D WR	Qual Device: SN74HC563D WR	QBS Process Reference: SN74HCS74QPWR Q1	QBS Package Reference: SN65LBC170DW QMI505MT CU STD	QBS Package Reference: SN74AC240QPWR SV	QBS Package Reference: <u>SN74HCS273QPWR</u> <u>Q1</u>
AC	Autoclave 121C	96 Hours	-	-	-	3/231/0	3/231/0	3/231/0	1/77/0
CDM	ESD - CDM	1500V	1/3/0	-	1/3/0	1/3/0	-	-	1/3/0
ED	Electrical Characterizati on	Per datasheet paramete rs	Pass	-	Pass	Pass	Pass	Pass	Pass
ELF R	Early Life Failure Rate, 125C	48 Hours	-	-	-	3/2400/0	-	-	-
HAS T	Biased HAST, 130C/85%RH	96 Hours	-	-	-	3/231/0	-	3/231/0	1/77/0
НВМ	ESD - HBM	4000V	1/3/0	-	1/3/0	1/3/0	-	-	1/3/0
HTO L	Life Test, 150C	300 Hours	-	-	-	3/231/0	-	-	1/77/0
HTS L	High Temp Storage Bake 170C	420 Hours	-	-	-	-	3/231/0	-	-
LU	Latch-up	(Per JESD78)	1/6/0	-	1/6/0	1/6/0	-	-	1/6/0
PC	Preconditionin g	Level 1- 260C	-	-	-	No Fails	No Fails	No Fails	No Fails
TC	Temperature Cycle, - 65/150C	500 Cycles	-	1/77/0	-	3/231/0	3/231/0	3/231/0	1/77/0
WBP	Wire Bond Pull (Cpk>1.67)	Wires	-	-	-	3/90/0	-	3/90/0	1/30/0

Туре	Test Name / Condition	Duration	Qual Device: <u>CD74HC564M</u> <u>96</u>	Qual Device: SN74HC273D WR	Qual Device: SN74HC563D WR	QBS Process Reference: SN74HCS74QPWR Q1	QBS Package Reference: <u>SN65LBC170DW QMI505MT CU</u> <u>STD</u>	QBS Package Reference: <u>SN74AC240QPWR</u> <u>SV</u>	QBS Package Reference: SN74HCS273QPWR Q1
WBS	Wire Bond Shear (Cpk>1.67)	Wires	-	-	-	3/90/0	-	3/90/0	1/30/0

Туре	Test Name / Condition	Duration	QBS Package Reference: SN74LVC541ADW_QMI505MT_AU_STD
AC	Autoclave 121C	Autoclave 121C 96 Hours	
ED	Electrical Distributions	Per datasheet parameters	Pass
HTSL	High Temp Storage Bake 170C	420 Hours	3/231/0
TC	Temperature Cycle, -65/150C	500 Cycles	3/231/0

- QBS: Qual By Similarity

- QBS; Qual By Similarity
 Qual Device SN74HC563DWR is qualified at LEVEL1-260C
 Qual Device CD74HC564M96 is qualified at LEVEL1-260C
 Qual Device SN74HC273DWR is qualified at LEVEL1-260C
 Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- Preconditioning was performed for Autoclave, Unbiased HAS1, 1HB/Biased HAS1, 1 emperature Cycle, 1 nermal Shock, and HISL, as applicable

 The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours

 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

 Quality and Environmental data is available at Tl's external Web site: http://www.ti.com/

 Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20210215-138613



Selective Disclosure

Approve Date 14-Sep-2021

Qualification Results Data Displayed as: Number of lots / Total sample size / Total failed

Туре	Test Name / Condition	Duration	Qual Device: SN74HC273DBR	QBS Product Reference: SN74HC273PWR	QBS Product Reference: SN74HC541PWR	QBS Product Reference: SN74HC574PWR	QBS Process Reference: SN74HCS273QPWRQ1	QBS Package Reference: 1M16374QDLREP	QBS Package Reference: 1R16214CDL
AC	Autoclave 121C	96 Hours	-	-	-	-	1/77/0	3/231/0	3/231/0
CDM	ESD - CDM	1500 V	1/3/0	1/3/0	1/3/0	1/3/0	1/3/0	-	-
ED	Electrical Characterization	Per Datasheet Parameters	-	-	-	-	Pass	Pass	Pass
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	-	-	1/77/0	-	-
НВМ	ESD - HBM	5000V	-	1/3/0	1/3/0	1/3/0	-	-	-
HTOL	Life Test, 150C	300 Hours	-	-	-	-	1/77/0	-	-
HTSL	High Temp Storage Bake 150C	1000 Hours	-	-	-	-	1/45/0	-	-
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	-	-	-	3/231/0	-
LU	Latch-up	(JESD78)	-	1/6/0	1/6/0	1/6/0	1/6/0	-	-
PC	Automotive Preconditioning Level 1	(Level 1- 260C)	-	-	-	-	No Fails	-	-
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	-	-	1/77/0	3/231/0	4/308/0
WBP	Bond Pull	Wires	1/76/0	-	-	-	-	-	-
WBS	Ball Bond Shear	Wires	1/76/0	-	-	-	-	-	-

Type	Test Name / Condition	Duration	QBS Package Reference: BQ77PL900DL	QBS Package Reference: <u>SN75976A1DL</u>	QBS Package Reference: <u>TLC5920DLR</u>		
AC	Autoclave 121C	96 Hours	-	3/231/0	-		
ED	Electrical Characterization	Per Data	-	1/Pass	-		
HTSL	High Temp Storage Bake 170C	420 Hours	-	3/231/0	-		
тс	Temperature Cycle, -65/150C	500 Cycles	3/231/0	3/231/0	4/308/0		

- QBS: Qual By Similarity
- Qual Device SN74HC273DBR is qualified at LEVEL1-260C
 Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

 The following are equivalent HTOL options based on an activation energy of 0.7eV: 150C/1k Hours, 140C/420 Hours, 150C/300 Hours, and 155C/240 Hours

 The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/ Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20210125-138295





Oualification Report

BD3 HC/HCT PCN Devices: PW/N Commercial - CD74HC112PWR, SN74HC175PWR, SN74HC368PWR, SN74HC244PWR, SN74HC244APWR, CD74HC688PWR, SN74HC1240PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1244PWR, SN74HC1373PWR, SN74HC1373PWR, SN74HC1373PWR, SN74HC1374PWR, SN74HC1374PWR,

Approve Date 14-DECEMBER -2021

Product Attributes

Attributes	Qual Device:	Qual Device:	Qual Device:	Qual Device:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:	QBS Reference:
Attributes	CD74HC112PWR	SN74HCT373PWR	SN74HC688PWR	SN74HC368PWR	SN74HCT540N	SN74LS03N	SN74HCS74QPWRQ1	SN74HCS74PWR	TPIC6A596NE	SN74HCS273QPWRQ1
Die Attributes					-					
Wafer Fab Supplier	RFAB	RFAB	RFAB	RFAB	SH-BIP-1	SH-BIP-1	RFAB	RFAB	DL-LIN	RFAB
Wafer Process	LBC9	LBC9	LBC9	LBC9	74HC	JI1	LBC9	LBC9	15P1_PRISM	LBC9
Die Size (L,W) (um)	520 x 679	520 x 679	520 x 679	520 x 679	1447.8 × 2336.8	767.9944 x 951.992	460 x 510	460 x 510	2743.2 x 2489.2	520 x 679
Passivation	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride	Silicon Oxynitride
Package Attributes										
Assembly Site	TFME	MLA	MLA	MLA	MLA	MLA	MLA	TFME	MLA	MLA
Package Group	TSSOP	TSSOP	TSSOP	TSSOP	PDIP	PDIP	TSSOP	TSSOP	PDIP	TSSOP
Package Designator	PW	PW	PW	PW	N	N	PW	PW	NE	PW
Package Size (mm)	5 x 4.4	6.5 x 4.4	6.5 x 4.4	5 x 4.4	24.33 x 6.35	19.3 x 6.35	5 x 4.4	5 x 4.4	24.51 x 6.86	6.5 x 4.4
Body Thickness (mm)	1	1	1	1	4.57	3.9	1	1	4.57	1
Pin Count	16	20	20	16	20	14	14	14	20	20
Lead Finish	MATTE SN	NIPDAU	NIPDAU	NIPDAU	NIPDAU	NIPDAU	NIPDAU	MATTE SN	NIPDAU	NIPDAU
Lead Pitch(mm)	0.65	0.65	0.65	0.65	2.54	2.54	0.65	0.65	2.54	0.65
Mount Compound Supplier	HENKEL	HENKEL	HENKEL	HENKEL	HENKEL	HENKEL	HENKEL	HENKEL	HENKEL	HENKEL
Mount Compound Supplier Number	ABLEBOND 2000T	QMI 505MT	QMI 505MT	QMI 505MT	QMI 505MT	QMI 505MT	QMI 505MT	ABLEBOND 2000T	QMI 505MT	QMI 505MT
Mold Compound Supplier	HITACHI	SUMITOMO	SUMITOMO	SUMITOMO	SUMITOMO	SUMITOMO	SUMITOMO	HITACHI	SUMITOMO	SUMITOMO
Mold Compound Supplier Number	CEL-8240HF-10NF- D1	EME-G610TA	EME-G610TA	EME-G610TA	EME-G633C	EME-G633C	EME-G610TA	CEL-8240HF-10NF- D1	EME-G633C	EME-G610TA
Bond Wire Composition	CU	CU	CU	CU	CU	CU	CU	CU	AU	CU
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0

- QBS: Qual By Similarity
 Qual Device CD74HC112PWR is qualified at MSL1 260C

- Qual Device SN74HCT373PWP: is qualified at MSL1 260C
 Qual Device SN74HC688PWP: is qualified at MSL1 260C
 Qual Device SN74HC588PWP: is qualified at MSL1 260C
 Qual Device SN74HC538PWP: is qualified at MSL1 260C
 Qual Device SN74HCT54PWP: is qualified at MSL1 260C
 Qual Device SN74HCT34PWP: is qualified at MSL1 260C
 Qual Device SN74HC734PWP: is qualified at MSL1 260C
 Qual Device SN74HC734PWP: is qualified at MSL1 260C
 Qual Device CN74HC112PWP: is qualified at MSL1 260C
 Qual Device CD74HC112PWP: is qualified at MSL1 260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: CD74HC112PWR	Qual Device: SN74HCT373PWR	Qual Device: SN74HC688PWR	Qual Device: SN74HC368PWR	QBS Reference: SN74HCT540N	QBS Reference: SN74LS03N	QBS Reference: SN74HCS74QPWRQ1	QBS Reference: SN74HCS74PWR	QBS Reference: TPIC6A596NE	QBS Reference: SN74HCS273QPWRQ1
HAST	A2	Biased HAST	130C/85%PH	96 Hours	0.55	22		(2)	-		3/231/0	3/231/0	3/231/0	1/77/0
UHAST	АЗ	Autoclave	121C/15psig	96 Hours	7.65		-	-	3/231/0	3/231/0		3/231/0	3/231/0	1/77/0
UHAST	АЗ	Unbiased HAST	130C/85%PH	96 Hours	0.20	137	-	-			3/231/0	3/231/0	153	50
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	1/4/	1-2	-	-	3/231/0	3/231/0		3/231/0	3/231/0	
HTSL	A6	High Temperature Storage Life	150C	1000 Hours		-		-	-	2	2	3/135/0		1/45/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours		-		-	3/135/0	3/135/0	-	-		-
HTSL	A6	High Temperature Storage Life	175C	500 Hours	é	٠	-	-		-	is .		3/135/0	•
HTOL	В1	Life Test	125C	1000 Hours	340	640	-		-	-	3/231/0	-	3/231/0	
HTOL	B1	Life Test	150C	300 Hours	120	-	-	-		2	- 12	-	3.0	1/77/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	(4)				-		3/2400/0		600	•
ESD	E2	ESD CDM	120	1500 Volts	1/3/0	1/3/0	1/3/0	1/3/0	-	-	12	3/9/0	120	
ESD	E2	ESD HBM		4000 Volts	2.00	1/3/0	1/3/0	1/3/0	-		e.		1991	-
LU	E4	Latch-Up	Per JESD78			1/3/0	1/3/0	1/3/0				-		
CHAR	E5	Electrical Characterization	Per Datasheet Parameters		381	1/30/0	1/30/0	1/30/0	-	-	3/90/0	3/90/0	3/90/0	3/90/0

- Preconditioning was performed for Autoclave, Unbiased HAST, THBBlased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
 The following are equivalent HTDL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C480 Hours, 150C/300 Hours, and 155C/240 Hours
 The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C420 Hours
 The following are equivalent Temp Cycle options per JESD47: 55C/125C/700 Cycles and -65C/150C/500 Cycles

 Quality and Environmental data is available at Trs external Web site: http://www.st.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: R-CHG-2110-006

For questions regarding this notice, e-mails can be sent to the contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
WW PCN Team	PCN www admin_team@list.ti.com

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.